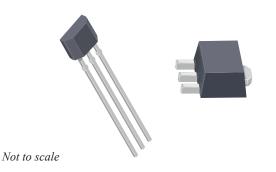


# **Features and Benefits**

- Chopper stabilization for stable switchpoints throughout operating temperature range
- Externally programmable:
- Operate point (through the VCC pin)
- Output polarity
- Output fall time for reduced EMI in automotive applications
- On-board voltage regulator for 3 to 24 V operation
- On-chip protection against:
- Supply transients
- Output short-circuits
- Reverse battery condition

# Packages: 3-pin SIP (suffix UA) and 3-pin SOT89 (suffix LT)



# Description

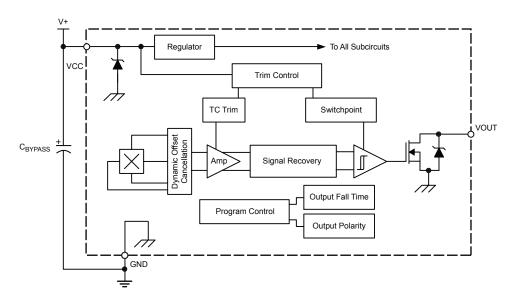
The A1128 is a field-programmable, unipolar Hall-effect switch designed for use in high-temperature applications. This device uses a chopper-stabilization technique to eliminate offset inherent in single-element devices.

The devices are externally programmable. A wide range of programmability is available on the magnetic operate point,  $B_{OP}$ , while the hysteresis remains fixed. This advanced feature allows optimization of the sensor IC switchpoint and can drastically reduce the effects of mechanical placement tolerances found in end-use production environments.

A proprietary dynamic offset cancellation technique, with an internal high-frequency clock, reduces the residual offset voltage, which is normally caused by device overmolding, temperature dependencies, and thermal stress. Having the Hall element and amplifier in a single chip minimizes many problems normally associated with low-level analog signals.

Two package styles provide a magnetically optimized package for most applications. Type LT is a miniature SOT89/TO-243AA surface mount package that is thermally enhanced with an exposed ground tab, and type UA is a three-lead ultramini SIP for through-hole mounting. The packages are lead (Pb) free, with 100% matte tin plated leadframes.

# **Functional Block Diagram**



#### **Selection Guide**

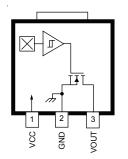
Part Number P	acking*	Package	
A1128LLTTR-T 7-in. reel,	1000 pieces/reel	3-pin SOT89/TO-243 surface mount	
A1128LUA-T Bulk, 500	pieces/bag	3-pin SIP through hole	

\*Contact Allegro<sup>™</sup> for additional packaging options.

#### **Absolute Maximum Ratings**

Characteristic	Symbol	Notes	Rating	Unit
Forward Supply Voltage	V <sub>CC</sub>		28	V
Reverse Supply Voltage	V <sub>RCC</sub>		-18	V
Forward Output Voltage	V <sub>OUT</sub>		26.5	V
Reverse Output Voltage	V <sub>ROUT</sub>		-0.7	V
Output Sink Current	I <sub>OUT(SINK)</sub>	VCC to VOUT	20	mA
Operating Ambient Temperature	T <sub>A</sub>	L temperature range	-40 to 150	°C
Maximum Junction Temperature	T <sub>J</sub> (max)		165	°C
Storage Temperature	T <sub>stg</sub>		-65 to 170	°C

### **Pin-out Diagrams**



LT Package

UA Package

#### **Terminal List Table**

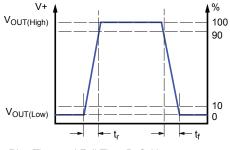
Number	Name	Function
1	VCC	Input power supply
2	GND	Ground
3	VOUT	Output signal



## **OPERATING CHARACTERISTICS** Valid with $T_A = -40^{\circ}$ C to 150°C, $C_{BYPASS} = 0.1 \mu$ F, $V_{CC} = 12$ V, unless otherwise noted

Characteristic	Symbol	Test Conditions		Min.	Тур.	Max.	Unit <sup>1</sup>
ELECTRICAL CHARACTERISTICS	6						
Supply Voltage	V <sub>CC</sub>			3	12	24	V
Supply Current	I <sub>CC</sub>	No load on V	/OUT	_	-	5.5	mA
Supply Zener Clamp Voltage	V <sub>ZSUPPLY</sub>	T <sub>A</sub> = 25°C, I <sub>0</sub>	<sub>CC</sub> = I <sub>CC</sub> (max) + 3 mA	28	-	_	V
Output Zener Clamp Voltage	V <sub>ZOUTPUT</sub>	I <sub>OUT</sub> = 3 mA		28	-	-	V
Reverse Battery Zener	V <sub>RCC</sub>			-	-	-18	V
Reverse Battery Current	I <sub>RCC</sub>	V <sub>CC</sub> = -18 V	1	-5	-	-	mA
Chopping Frequency	f <sub>C</sub>			-	400	-	kHz
POWER-ON CHARACTERISTICS							
Power-On Time	t <sub>PO</sub>	T <sub>A</sub> = 25°C; C	C <sub>LOAD</sub> (PROBE) = 10 pF	-	-	30	μs
Power-On State <sup>2</sup>	POS	POL = 0; B < $B_{RP}$ , t > $t_{on}$		-	High	-	_
Power-On State <sup>2</sup>		POL = 1; B ·	_	Low	-	_	
OUTPUT STAGE CHARACTERIST	ICS						
Output Saturation Voltage	V <sub>OUT(sat)</sub>	I <sub>OUT</sub> = 20 mA		-	175	400	mV
Output Leakage Current	I <sub>OFF</sub>	V <sub>OUT</sub> = 24 V; Switch state = Off		-	-	10	μA
Output Current Limit	I <sub>OUT(lim)</sub>	Short-Circuit Protection, Output = On		30	-	90	mA
Output Rise Time <sup>3,4</sup>		V <sub>CC</sub> = 12 V, R <sub>LOAD</sub> = 820 Ω, C <sub>LOAD</sub> = 10 pF		-	-	2	μs
Output Rise Times,4	t <sub>r</sub>	V <sub>CC</sub> = 12 V, R <sub>LOAD</sub> = 2 kΩ, C <sub>LOAD</sub> = 4.7 nF		-	21	-	μs
		FALL = 0, V <sub>0</sub> C <sub>LOAD</sub> = 10	<sub>CC</sub> = 12 V, R <sub>LOAD</sub> = 820 Ω, pF	-	-	2	μs
		FALL = 1, $V_{CC}$ = 12 V, $R_{LOAD}$ = 2 k $\Omega$ , C <sub>LOAD</sub> = 4.7 nF		_	6.5	-	μs
Output Fall Time <sup>4</sup>	t <sub>f</sub>	FALL = 2, $V_{CC}$ = 12 V, $R_{LOAD}$ = 2 k $\Omega$ , C <sub>LOAD</sub> = 4.7 nF		_	10	-	μs
		FALL = 3, V <sub>CC</sub> = 12 V, R <sub>LOAD</sub> = 2 kΩ, C <sub>LOAD</sub> = 4.7 nF		_	12.5	-	μs
			B > B <sub>OP</sub>	_	Low	-	_
Outout Data at 2		POL = 0	B < B <sub>RP</sub>	_	High	-	_
Output Polarity <sup>2</sup>	POL		B > B <sub>OP</sub>	_	High	-	_
		POL = 1	B < B <sub>RP</sub>	_	Low	_	_

Continued on the next page ...



Rise Time and Fall Time Definitions



# **OPERATING CHARACTERISTICS** (continued) Valid with $T_A = -40^{\circ}$ C to 150°C, $C_{BYPASS} = 0.1 \mu$ F, $V_{CC} = 12 V$ ,

unless otherwise noted

Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Unit <sup>1</sup>
MAGNETIC CHARACTERISTICS valid	$V_{\rm CC}$ = 3 to 24	V, $T_J \leq T_J(max)$ , unless otherwise noted				
Pre-Programming B <sub>OP</sub> Target		T <sub>A</sub> = 25°C, BOPPOL = 0	-	-35	-	G
	B <sub>OPinit</sub>	T <sub>A</sub> = 25°C, BOPPOL = 1	-	35	-	G
Quitable sigt The second Drift5		LT package, B <sub>OP</sub> = ±650 G	-0.14	-0.03	0.08	%/°C
Switchpoint Thermal Drift <sup>5</sup>	ΔB <sub>OP</sub>	UA package, B <sub>OP</sub> = ±650 G	-0.08	0.00	0.08	%/°C
Hysteresis	B <sub>hys</sub>	B <sub>OP</sub> - B <sub>RP</sub>	5	15	30	G
PROGRAMMING CHARACTERISTICS						
Switchpoint Magnitude Selection Bits	Bit <sub>BOPSEL</sub>		-	8	-	Bit
Switchpoint Polarity Bits	Bit <sub>BOPPOL</sub>		-	1	-	Bit
Output Polarity Bits	Bit <sub>POL</sub>		-	1	-	Bit
Fall Time Bits	Bit <sub>FALL</sub>		-	2	-	Bit
Device Lock Bits	BitLOCK		-	1	-	Bit
Programmable B <sub>OP</sub> Range		T <sub>A</sub> = 25°C, BOPPOL = 1 (minimum at BOPSEL = 255, maximum at BOPSEL = 0)	-650	_	20	G
	B <sub>OP</sub>	T <sub>A</sub> = 25°C, BOPPOL = 0 (minimum at BOPSEL = 0, maximum at BOPSEL = 255)	-20	_	650	G
B <sub>OP</sub> Step Size	Res <sub>BOP</sub>	Bit = LSB of BOPSEL	-	4	8	G

<sup>1</sup>1 G (gauss) = 0.1 mT (millitesla).

<sup>2</sup>Output state when device configured as shown in figure 1.

<sup>3</sup>Output Rise Time is governed by external circuit tied to VOUT.

<sup>4</sup>Measured from 10% to 90% steady state output.

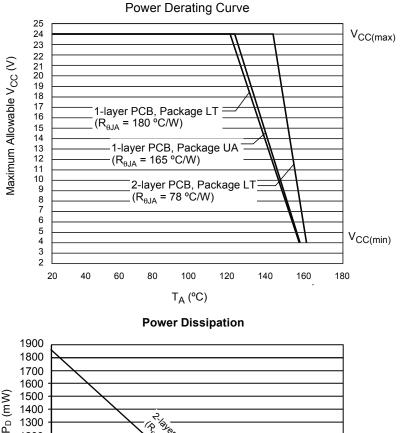
<sup>5</sup>Internal trimming utilized to minimize switchpoint drift across the operating temperature range.

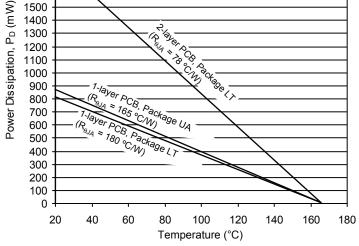


#### THERMAL CHARACTERISTICS may require derating at maximum conditions, see application information

Characteristic	Symbol	Test Conditions*	Value	Units
Package Thermal Resistance		Package UA, 1-layer PCB with copper limited to solder pads		°C/W
	$R_{\theta JA}$	Package LT, 1-layer PCB with copper limited to solder pads	180	°C/W
		Package LT, 2-layer PCB with 0.94 in <sup>2</sup> copper each side	78	°C/W

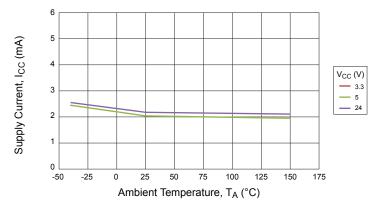
\*Additional thermal information available on Allegro website.





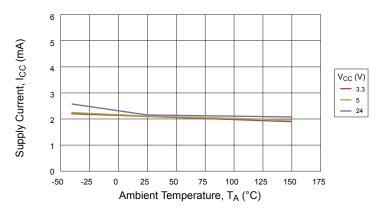


# **Characteristic Performance**

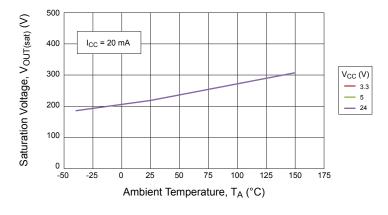


## Supply Current (On) versus Ambient Temperature











#### 100 Q RLOAD 1.2 kΩ vcc (A) A1128 IC Output VOUT CRYPASS 0.1 µF А $C_{\text{LOAD}}$ GND 120 pF 2 Α Tie to device pins using traces as short as possible

# **Application Information**

Figure 1. Typical Application Circuit

### **Chopper Stabilization Technique**

When using Hall-effect technology, a limiting factor for switch point accuracy is the small signal voltage developed across the Hall element. This voltage is disproportionally small relative to the offset that can be produced at the output of the Hall sensor IC. This makes it difficult to process the signal while maintaining an accurate, reliable output over the specified operating temperature and voltage ranges. Chopper stabilization is a unique approach used to minimize Hall offset on the chip. Allegro employs a technique to remove key sources of the output drift induced by thermal and mechanical stresses. This offset reduction technique is based on a signal modulation-demodulation process. The undesired offset signal is separated from the magnetic fieldinduced signal in the frequency domain, through modulation. The subsequent demodulation acts as a modulation process for the offset, causing the magnetic field-induced signal to recover its original spectrum at base band, while the DC offset becomes a high-frequency signal. The magnetic-sourced signal then can

pass through a low-pass filter, while the modulated DC offset is suppressed. In addition to the removal of the thermal and stress related offset, this novel technique also reduces the amount of thermal noise in the Hall sensor IC while completely removing the modulated residue resulting from the chopper operation. The chopper stabilization technique uses a high frequency sampling clock. For demodulation process, a sample and hold technique is used. This high-frequency operation allows a greater sampling rate, which results in higher accuracy and faster signal-processing capability. This approach desensitizes the chip to the effects of thermal and mechanical stresses, and produces devices that have extremely stable quiescent Hall output voltages and precise recoverability after temperature cycling. This technique is made possible through the use of a BiCMOS process, which allows the use of low-offset, low-noise amplifiers in combination with highdensity logic integration and sample-and-hold circuits.

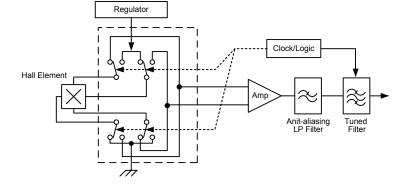


Figure 2. Concept of Chopper Stabilization Technique



# **Functional Description**

When the Output Polarity bit is not set (POL = 0), the A1128 output switches on after the magnetic field at the Hall sensor IC exceeds the operate point threshold,  $B_{OP}$ . When the magnetic field is reduced to below the release point threshold,  $B_{RP}$ , the device output switches off. The difference between the magnetic operate and release points is called the hysteresis of the device,  $B_{HYS}$ . In the alternative case, in which the Output Polarity bit is set (POL = 1), the A1128 output switches off when the magnetic field

at the Hall sensor IC exceeds the operate point threshold,  $B_{OP}$ . When the magnetic field is reduced to below the release point threshold,  $B_{RP}$ , the device output switches on.

Note that for the Pre-Programming  $B_{OP}$  Target,  $B_{OPinit}$ , when BOPPOL = 0 although the operating range is 0 to B+, the initial  $B_{OPinit}$  is actually negative, and likewise, when BOPPOL = 1, although the operating range 0 to B-, the initial  $B_{OPinit}$  is actually positive.

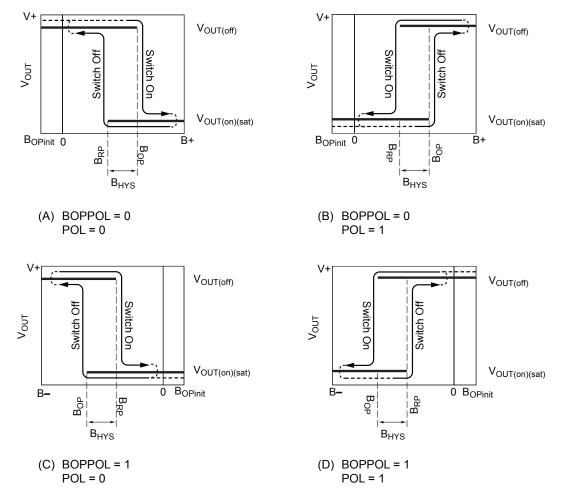


Figure 3. Hysteresis Diagrams. These plots demonstrate the behavior of the A1128 with the applied magnetic field impinging on the branded face of the device case (refer to Package Outline Drawings section). On the horizontal axis, the B+ direction indicates increasing south or decreasing north magnetic flux density, and the B– direction indicates increasing south magnetic flux density.



# **Programming Guidelines**

#### Overview

Programming is accomplished by sending a series of input voltage pulses serially through the VCC (supply) pin of the device. A unique combination of different voltage level pulses controls the internal programming logic of the device to select a desired programmable parameter and change its value. There are three voltage levels that must be taken into account when programming. These levels are referred to as *high* ( $V_{PH}$ ), *mid* ( $V_{PM}$ ), and *low* ( $V_{PL}$ ).

The A1128 features three programmable modes, Try mode, Blow mode, and Read mode:

- In Try mode, programmable parameter values are set and measured simultaneously. A parameter value is stored temporarily, and reset after cycling the supply voltage.
- In Blow mode, the value of a programmable parameter may be permanently set by blowing solid-state fuses internal to the device. Device locking is also accomplished in this mode.
- In Read mode, each bit may be verified as blown or not blown.

The programming sequence is designed to help prevent the device from being programmed accidentally; for example, as a result of noise on the supply line. Note that, for all programming modes, no parameter programming registers are accessible after the devicelevel LOCK bit is set. The only function that remains accessible is the overall Fuse Checking feature.

Although any programmable variable power supply can be used to generate the pulse waveforms, for design evaluations, Allegro highly recommends using the Allegro Sensor IC Evaluation Kit, available on the Allegro website On-line Store. The manual for that kit is available for download free of charge, and provides additional information on programming these devices. (Note: This kit is not recommended for production purposes.)

#### **Definition of Terms**

**Register** The section of the programming logic that controls the choice of programmable modes and parameters.

**Bit Field** The internal fuses unique to each register, represented as a binary number. Changing the bit field settings of a particular

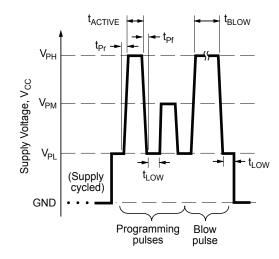


Figure 4. Programming pulse definitions (see table 1)

Characteristics	Symbol	Notes	Min.	Тур.	Max.	Unit
	V <sub>PL</sub>		4.5	5	5.5	V
Programming Voltage	V <sub>PM</sub>	Measured at the VCC pin		_	14	V
	V <sub>PH</sub>			-	27	V
Programming Current	I <sub>PP</sub>	$V_{CC}$ = 5 $\rightarrow$ 26 V, $C_{BLOW}$ = 0.1 $\mu F$ (min); minimum supply current required to ensure proper fuse blowing.		_	-	mA
	t <sub>LOW</sub>	t <sub>LOW</sub> Duration of V <sub>PL</sub> separating pulses at V <sub>PM</sub> or V <sub>PH</sub>		-	-	μs
Pulse Width	t <sub>ACTIVE</sub>	Duration of pulses at $V_{PM}$ or $V_{PH}$ for key/code selection	20	-	-	μs
	t <sub>BLOW</sub>	Duration of pulse at V <sub>PH</sub> for fuse blowing		100	-	μs
Pulse Rise Time	t <sub>Pr</sub>	$V_{PL}$ to $V_{PM}$ or $V_{PL}$ to $V_{PH}$		_	100	μs
Pulse Fall Time	t <sub>Pf</sub>	$V_{PM}$ to $V_{PL}$ or $V_{PH}$ to $V_{PL}$		_	100	μs
Blow Pulse Slew Rate	SR <sub>BLOW</sub>		0.375	_	-	V/µs

#### Table 1. Programming Pulse Requirements, Protocol at $T_{\Delta} = 25^{\circ}C$



# A1128

register causes its programmable parameter to change, based on the internal programming logic.

Key A series of voltage pulses used to select a register or mode.

**Code** The number used to identify the combination of fuses activated in a bit field, expressed as the decimal equivalent of the binary value. The LSB of a bit field is denoted as code 1, or bit 0.

**Addressing** Increasing the bit field code of a selected register by serially applying a pulse train through the VCC pin of the device. Each parameter can be measured during the addressing process, but the internal fuses must be blown before the programming code (and parameter value) becomes permanent.

**Fuse Blowing** Applying a high voltage pulse of sufficient duration to permanently set an addressed bit by blowing a fuse internal to the device. Once a bit (fuse) has been blown, it cannot be reset.

**Blow Pulse** A high voltage pulse of sufficient duration to blow the addressed fuse.

**Cycling the Supply** Powering-down, and then powering-up the supply voltage. Cycling the supply is used to clear the programming settings in Try mode.

# **Programming Procedure**

Programming involves selection of a register and mode, and then setting values for parameters in the register for evaluation or fuse blowing. Figure 8 provides an overview state diagram.

### **Register Selection**

Each programmable parameter can be accessed through a specific register. To select a register, from the Initial state, a sequence of voltage pulses consisting of one  $V_{PH}$  pulse, one  $V_{PM}$  pulse, and then a unique combination of  $V_{PH}$  and  $V_{PM}$  pulses, is applied serially to the VCC pin (with no  $V_{CC}$  supply interruptions). This sequence of pulses is called the *key*, and uniquely identifies each register. An example register selection key is shown in figure 5.

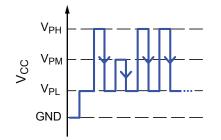


Figure 5. Example of Try mode register selection pulses, for the  $\rm B_{OP}$  Negative Trim, Up-Counting register.

To simplify Try mode, the A1128 provides a set of four virtual registers, one for each combination of:  $B_{OP}$  selection (BOPSEL),  $B_{OP}$  polarity (BOPPOL), and a facility for transiting  $B_{OP}$  magnitude values in an increasing or decreasing sequence. These registers also allow wrapping back to the beginning of the register after transiting the register.

## Mode Selection

The same physical registers are used for all programming modes. To distinguish Blow mode and Read mode, when selecting the registers an additional pulse sequence consisting of eleven  $V_{PM}$  pulses followed by one  $V_{PH}$  pulse is added to the key. The combined register and mode keys are shown in table 3.

## Try Mode

In Try mode, the bit field addressing is accomplished by applying a series of V<sub>PM</sub> pulses to the VCC pin of the device, as shown in figure 6. Each pulse increases the total bit field value of the selected parameter, increasing by one on the falling edge of each additional V<sub>PM</sub> pulse. When addressing a bit field in Try mode, the number of V<sub>PM</sub> pulses is represented by a decimal number called a code. Addressing activates the corresponding fuse locations in the given bit field by increasing the binary value of an internal DAC, up to the maximum possible code. As the value of the bit field code increases, the value of the programmable parameter changes. Measurements can be taken after each V<sub>PM</sub> pulse to determine if the desired result for the programmable parameter has been reached. Cycling the supply voltage resets all the locations in the bit field that have un-blown fuses to their initial states. This should also be done before selection of a different register in Try mode.

When addressing a parameter in Try mode, the bit field address (code) defaults to the value 1, on the falling edge of the final register selection key  $V_{PH}$  pulse (see figure 6). A complete example is shown figure 10. Note that, in the four  $B_{OP}$  selection virtual registers, after the maximum code is entered, the next VPM pulse wraps back to the beginning of the register, and selects code 0.

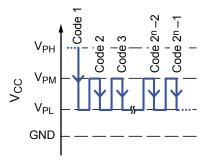


Figure 6. Try mode bit field addressing pulses.



The four  $B_{OP}$  selecting virtual registers allow the programmer to adjust the  $B_{OP}$  parameter for use in north or south magnetic fields. In addition, values can be traversed from low to high, or from high to low. Figure 12 shows the relationship between the  $B_{OP}$  parameter and the different Try mode registers. Note: See the Output Polarity section for information about setting the POL bit before using Try mode.

The FALL and POL fields are in the same register (FALL is bits 1:0, and POL is bit 2). Therefore, in Try mode both can be programmed simultaneously by adding the codes for the two parameters, and send the sum as the code. For example, sending code 7 (111) sets FALL to 3 (x11) and sets POL (1xx).

#### **Blow Mode**

After the required code is determined for a given parameter, its value can be set permanently by blowing individual fuses in the appropriate register bit field. Blowing is accomplished by selecting the register and mode selection key, followed by the appropriate bit field address, and ending the sequence with a Blow pulse. The Blow mode selection key is a sequence of eleven  $V_{PM}$  pulses followed by one  $V_{PH}$  pulse. The Blow pulse consists of a  $V_{PH}$  pulse of sufficient duration,  $t_{BLOW}$ , to permanently set an addressed bit by blowing a fuse internal to the device. The device power must be cycled after each individual fuse is blown.

Due to power requirements, a 0.1  $\mu$ F blowing capacitor, C<sub>BLOW</sub>, must be mounted between the VCC pin and the GND pin during programming, to ensure enough current is available to blow fuses. If programming in the application, C<sub>BYPASS</sub> (see figure 1) can serve the same purpose.

The fuse for each bit in the bit field must be blown individually. The A1128 built-in circuitry allows only one fuse at a time to be blown. During Blow mode, the bit field can be considered a "one-hot" shift register. Table 2 illustrates how to relate the number of  $V_{PM}$  pulses to the binary and decimal value for Blow mode bit field addressing. It should be noted that the simple relationship between the number of  $V_{PM}$  pulses and the required code is:

### $2^n = \text{Code},$

where n is the number of  $V_{PM}$  pulses, and the bit field has an initial state of decimal code 1 (binary 00000001). To correctly blow the required fuses, the code representing the required parameter value must be translated to a binary number. For example, as shown in figure 7, decimal code 5 is equivalent to the binary number 101. Therefore bit 2 must be addressed and blown, the device power supply cycled, and then bit 0 must be addressed and blown. The order of blowing bits, however, is not important. Blowing bit 0 first, and then bit 2 is acceptable. A complete example is shown in figure 11.

Note: After blowing, the programming is not reversible, even after cycling the supply power. Although a register bit field fuse cannot be reset after it is blown, additional bits within the same register can be blown at any time until the device is locked. For example, if bit 1 (binary 10) has been blown, it is still possible to blow bit 0. The end result would be binary 11 (decimal code 3).

## Locking the Device

After the required code for each parameter is programmed, the device can be locked to prevent further programming of any parameters. To do so, perform the following steps:

- 1. Ensure that the  $C_{BLOW}$  capacitor is mounted.
- 2. Select the Output/Lock Bit register key.
- 3. Select Blow mode selection key.
- 4. Address bit 4 (10000) by sending four  $V_{\text{PM}}$  pulses.

5. Send one Blow pulse, at  $I_{PP}$  and  $SR_{BLOW}\text{,}$  and sustain it for  $t_{BLOW}\text{.}$ 

- 6. Delay for a  $t_{LOW}$  interval, then power-down.
- 7. Optionally check all fuses.

## Table 2. Blow Mode Bit Field Addressing

		-
Quantity of V <sub>PM</sub> Pulses	Binary Register Bit Field	Decimal Equivalent Code
0	0000 0001	1
1	0000 0010	2
2	0000 0100	4
3	0000 1000	8
4	0001 0000	16
5	0010 0000	32
6	0100 0000	64
7	1000 0000	128

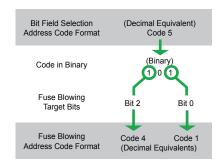


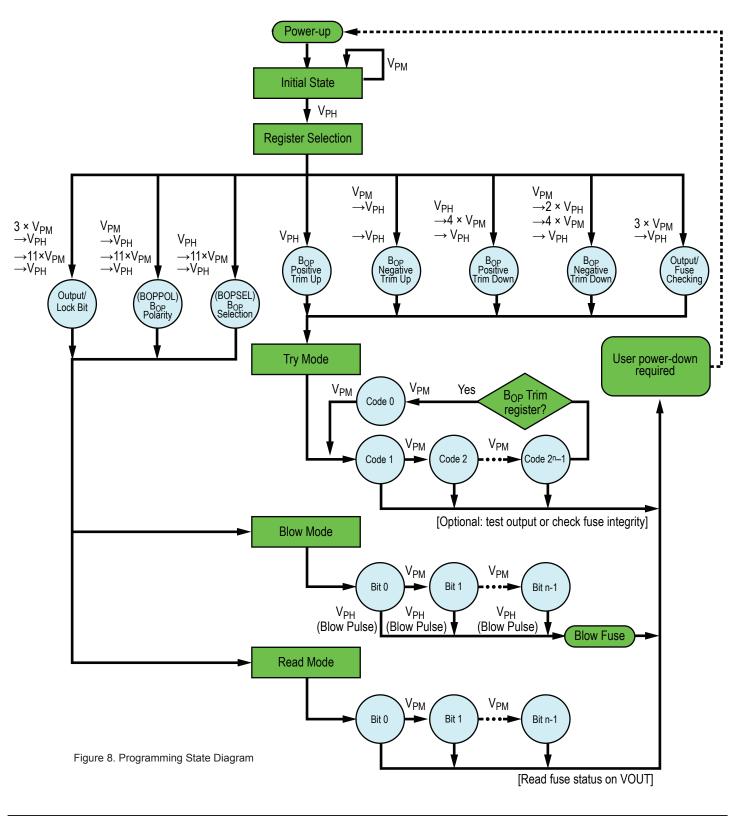
Figure 7. Example of code 5 broken into its binary components.



## Table 3. Programming Logic Table

Degister Name	Bit Field Add	ress (Code)			
Register Name [Selection Key]	Binary (MSB→LSB)	Decimal Equivalent	Notes		
Try Mode Register Selections		·			
B <sub>OP</sub> Positive, Trim Up-Counting	0000 0000	0	Increase $B_{OP}$ (South field). Code 1 automatically selected when register entered, wraps back to code 0.		
[2×V <sub>PH</sub> ]	1111 1111	255	B <sub>OP</sub> selection is at maximum value.		
B <sub>OP</sub> Negative, Trim Up-Counting	0000 0000	0	Increase $B_{OP}$ (North field). Code 1 automatically selected when register entered, wraps back to code 0.		
$[V_{PH} \rightarrow V_{PM} \rightarrow 2 \times V_{PH}]$	1111 1111	255	B <sub>OP</sub> selection is at maximum value.		
B <sub>OP</sub> Positive, Trim Down-Counting [2×V <sub>PH</sub> → 4×V <sub>PM</sub> → V <sub>PH</sub> ]	1111 1111	0	Decrease $B_{OP}$ (South field). Code 1 automatically selected when register entered, wraps back to code 0. Code is automatically inverted (code 1 selects $B_{OP}$ selection maximum value minus 1.)		
	0000 0000	255	B <sub>OP</sub> selection is at minimum value.		
B <sub>OP</sub> Negative, Trim Down-Counting $[V_{PH} \rightarrow V_{PM} \rightarrow 2 \times V_{PH}$	1111 1111	0	Decrease $B_{OP}$ (North field). Code 1 automatically selected when register entered, wraps back to code 0. Code is automatically inverted (code 1 selects $B_{OP}$ selection maximum value minus 1.)		
$\rightarrow$ 4 × V <sub>PM</sub> $\rightarrow$ V <sub>PH</sub> ]	0000 0000	255	B <sub>OP</sub> selection is at minimum value.		
	x01	1	Output Fall Time (FALL). Code 1 automatically selected. Minimum value.		
Output / Fuse Checking [ $V_{PH} \rightarrow 3 \times V_{PM} \rightarrow V_{PH}$ ]	x11	3	Output Fall Time (FALL) selection is at maximum value.		
	0xx	0	Output Polarity Bit (POL). Default, no fuse blowing required. POL = 0, see figures 3A and 3C.		
	1xx	4	Output Polarity Bit (POL). Code 1 automatically selected. POL = 1, see figures 3B and 3D. Code references a single bit only.		
	1000	8	Fuse Threshold Low Register. Code 1 automatically selected when register entered. Checks un-blown fuses. Code references a single bit only.		
	1001	9	Fuse Threshold High Register. Checks blown fuses.		
Blow or Read Mode Register Selec	ctions				
B <sub>OP</sub> Selection (BOPSEL)	0000 0000	0	${\sf B}_{\sf OP}$ magnitude selection. Default, no fuse blowing required. Minimum value, corresponding to ${\sf B}_{\sf OP}({\sf min}).$		
$[2 \times V_{PH} \rightarrow 11 \times V_{PM} \rightarrow V_{PH}]$	1111 1111	255	$B_{OP}$ magnitude selection. Maximum value, corresponding to $B_{OP}(max).$		
B <sub>OP</sub> Polarity (BOPPOL)	0	0	South field polarity. Default, no fuse blowing required.		
$[V_{PH} \rightarrow V_{PM} \rightarrow V_{PH} \rightarrow 11 \times V_{PM} \rightarrow V_{PH}]$	1	1	North field polarity. Code 1 (bit 0) automatically selected.		
	00	0	Output Fall Time (FALL). Default, no fuse blowing required.		
	11	3	Output Fall Time (FALL) selection is at maximum value. Code 1 (bit 0) automatically selected.		
	000	0	Output Polarity Bit (POL). Default, no fuse blowing required. POL = 0, see figures 3A and 3C.		
Output / Lock Bit [ $V_{PH} \rightarrow 3 \times V_{PM} \rightarrow V_{PH}$	100	4	Output Polarity Bit (POL). Code 1 (bit 0) automatically selected. Code refers to bit 2 only. POL = 1, see figures 3B and 3D.		
$\rightarrow$ 11 × V <sub>PM</sub> $\rightarrow$ V <sub>PH</sub> ]	10000	16	Lock bit (LOCK). Locks access to all registers with exception of Fuse Threshold registers. Code 1 (bit 0) automatically selected in Blow mode. Code refers to bit 5 only.		
	0 to 111 1111	_	Read mode bit values. Sequentially selects each bit in selected Blow mode register for reading bit status as blown or not blown. Code 1 (bit 0) automatically selected. Monitor VOUT after each pulse.		







## **Fuse Checking**

Incorporated in the A1128 is circuitry to simultaneously check the integrity of the fuse bits. The fuse checking feature is enabled by using the Fuse Checking registers, and while in Try mode, applying the codes shown in table 3. The register is only valid in Try mode and is available before or after the programming LOCK bit is set.

Selecting the Fuse Threshold High register checks that all blown fuses are properly blown. Selecting the Fuse Threshold Low register checks all un-blown fuses are properly intact. The supply current,  $I_{CC}$ , increases by 250  $\mu$ A if a marginal fuse is detected. If all fuses are correctly blown or fully intact, there will be no change in supply current.

## **Output Polarity**

When selecting the  $B_{OP}$  registers in Try mode, the output polarity is determined by the value of the Output Polarity bit (POL). The default value is POL = 0 (fuse un-blown). For applications that require the output states defined by POL = 1 (see Operating Characteristics table), it is recommended to first permanently blow the POL bit by selecting the Output / Lock bit register, and code 4. The output is then defined by POL = 1 when selecting the B<sub>OP</sub> Try mode registers. See table 3 for parameter details.

### Additional Guidelines

The additional guidelines in this section should be followed to ensure the proper behavior of these devices:

- $\bullet$  The power supply used for programming must be capable of delivering at least  $V_{PH}$  and 175 mA.
- $\bullet$  Be careful to observe the  $t_{\rm LOW}$  delay time before powering down the device after blowing each bit.
- Set the LOCK bit (only after all other parameters have been programmed and validated) to prevent any further programming of the device.

## Read Mode

The A1128 features a Read mode that allows the status of each programmable fuse to be read back individually. The status, blown or not blown, of the addressed fuse is determined by monitoring the state of the VOUT pin. A complete example is shown in figure 9.

Read mode uses the same register selection keys as Blow mode (see table 3), allowing direct addressing of the individual fuses in the BOPPOL and BOPSEL registers (do not inadvertently send a Blow pulse while in Read mode). After sending the register and mode selection keys, that is, after the falling edge of the final  $V_{PH}$  pulse in the key, the first bit (the LSB) is selected. Each additional  $V_{PM}$  pulse addresses the next bit in the selected register, up

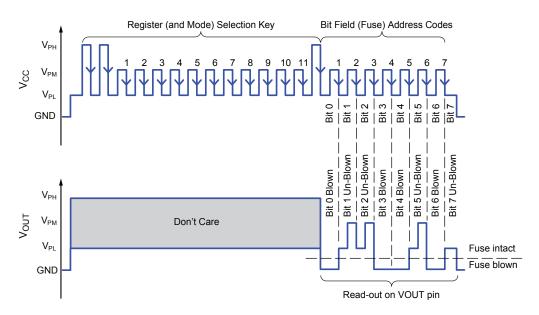


Figure 9. Read mode example. Pulse sequence for accessing the B<sub>OP</sub> Selection register (BOPSEL) and reading back the status of each of the eight bit fields. In this example, the code (blown fuses) is  $2^0 + 2^3 + 2^4 + 2^6 = 89$  (0101 1001). After each address pulse is sent, the voltage on the VOUT pin will be at GND for blown fuses and at V<sub>CC</sub> (at V<sub>PL</sub> or V<sub>PM</sub>) for un-blown fuses.



to the MSB. Read mode is available only before the LOCK bit has been set.

After the final  $V_{PH}$  key pulse, and after each  $V_{PM}$  address pulse, if  $V_{OUT}$  is low, the corresponding fuse can be considered blown

(the status of the Output Polarity bit, POL, does not affect Read mode output values, allowing POL to be tested also). If the output state is high, the fuse can be considered un-blown. During Read mode VOUT must be pulled high using a pull-up resistor (see  $R_{LOAD}$  in the Typical Application Circuit diagram).

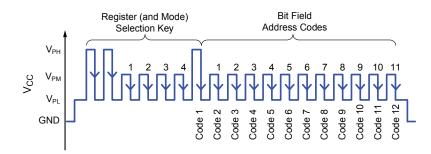


Figure 10. Example of Try mode programming pulses applied to the VCC pin. In this example,  $B_{OP}$  Positive Trim, Down-Counting register is addressed to code 12 by the eleven  $V_{PM}$  pulses (code 1 is selected automatically at the falling edge of the register-mode selection key).

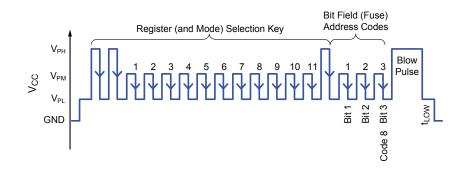


Figure 11. Example of Blow mode programming pulses applied to the VCC pin. In this example, the  $B_{OP}$  Magnitude Selection register (BOPSEL) is addressed to code 8 (bit 3, or 3  $V_{PM}$  pulses) and its value is permanently blown.



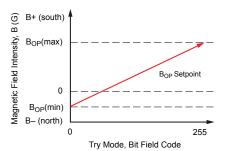
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# **B<sub>OP</sub> Selection**

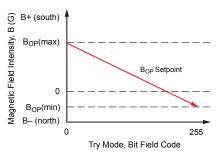
The A1128 allows accurate trimming of the magnetic operate point,  $B_{OP}$ , within the application. This programmable feature reduces effects due to mechanical placement tolerances and improves performance when used in proximity or vane sensing applications.

 $B_{OP}$  can be set to any value within the range allowed by the BOPSEL registers. This includes switchpoints of south or north polarity, and switchpoints at or near the zero crossing point for B. However, switching is recommended only within the Programmable  $B_{OP}$  Range, specified in the Operating Characteristics table. Trimming of  $B_{OP}$  is typically done in two stages. In the first stage,  $B_{OP}$  is adjusted temporarily using the Try mode programming features, to find the fuse value that corresponds to the optimum  $B_{OP}$ . After a value is determined, then it can be permanently set using the Blow mode features.

As an aid to programming the A1128 has several options available in Try Mode for adjusting the  $B_{OP}$  parameter. As shown in figure 12, these allow trimming of  $B_{OP}$  for operation in north or south polarity magnetic fields. In addition the  $B_{OP}$  parameter can either trim-up, start at the  $B_{OP}$  minimum value and increase to the maximum value, or trim-down, starting at the  $B_{OP}$  maximum value and decreasing to the minimum value.



(A) B<sub>OP</sub> Positive, Trim Up-Counting Register



(B) B<sub>OP</sub> Positive, Trim Down-Counting Register

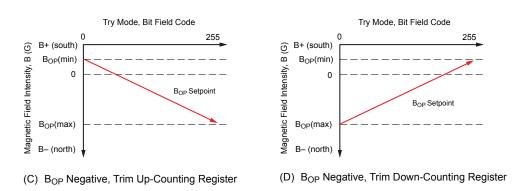


Figure 12. B<sub>OP</sub> profiles for each of the four B<sub>OP</sub> Selection virtual registers available in Try mode.



# **Power Derating**

The device must be operated below the maximum junction temperature of the device,  $T_J(max)$ . Under certain combinations of peak conditions, reliable operation may require derating supplied power or improving the heat dissipation properties of the application. This section presents a procedure for correlating factors affecting operating  $T_J$ . (Thermal data is also available on the Allegro MicroSystems website.)

The Package Thermal Resistance,  $R_{\theta JA}$ , is a figure of merit summarizing the ability of the application and the device to dissipate heat from the junction (die), through all paths to the ambient air. Its primary component is the Effective Thermal Conductivity, K, of the printed circuit board, including adjacent devices and traces. Radiation from the die through the device case,  $R_{\theta JC}$ , is relatively small component of  $R_{\theta JA}$ . Ambient air temperature,  $T_A$ , and air motion are significant external factors, damped by overmolding.

The effect of varying power levels (Power Dissipation,  $P_D$ ), can be estimated. The following formulas represent the fundamental relationships used to estimate  $T_J$ , at  $P_D$ .

$$P_{\rm D} = V_{\rm IN} \times I_{\rm IN} \tag{1}$$

$$\Delta T = P_D \times R_{\theta JA} \tag{2}$$

$$T_{J} = T_{A} + \Delta T \tag{3}$$

For example, given common conditions such as:  $T_A = 25$  °C,  $V_{IN} = 12$  V,  $I_{IN} = 4$  mA, and  $R_{\theta JA} = 140$  °C/W, then:

$$P_D = V_{IN} \times I_{IN} = 12 \text{ V} \times 4 \text{ mA} = 48 \text{ mW}$$
$$\Delta T = P_D \times R_{\theta JA} = 48 \text{ mW} \times 140 \text{ °C/W} = 7 \text{ °C}$$

 $T_{I} = T_{A} + \Delta T = 25^{\circ}C + 7^{\circ}C = 32^{\circ}C$ 

A worst-case estimate,  $P_D(max)$ , represents the maximum allowable power level, without exceeding  $T_J(max)$ , at a selected  $R_{\theta JA}$  and  $T_A$ .

*Example*: Reliability for  $V_{CC}$  at  $T_A=150^{\circ}$ C, package UA, using a single-layer PCB.

Observe the worst-case ratings for the device, specifically:  $R_{\theta JA}=165 \text{ °C/W}, T_J(max) = 165 \text{ °C}, V_{CC}(max) = 24 \text{ V}, \text{ and } I_{CC}(max) = 5.5 \text{ mA}.$ 

Calculate the maximum allowable power level,  $P_D(max)$ . First, invert equation 3:

$$\Delta T_{max} = T_J(max) - T_A = 165 \,^{\circ}\text{C} - 150 \,^{\circ}\text{C} = 15 \,^{\circ}\text{C}$$

This provides the allowable increase to  $T_J$  resulting from internal power dissipation. Then, invert equation 2:

$$P_{\rm D}(\text{max}) = \Delta T_{\rm max} \div R_{\theta JA} = 15^{\circ}\text{C} \div 165^{\circ}\text{C}/\text{W} = 91 \text{ mW}$$

Finally, invert equation 1 with respect to voltage:

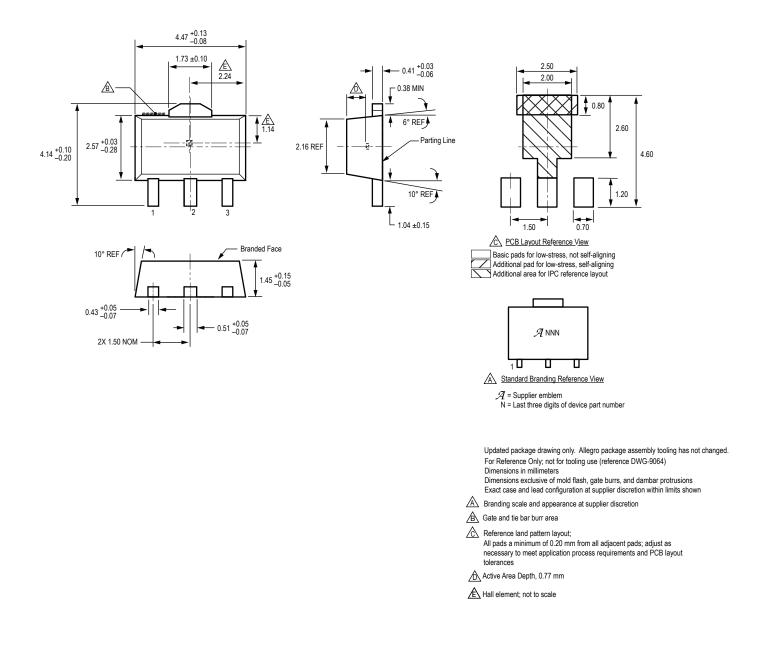
 $V_{CC}(est) = P_D(max) \div I_{CC}(max) = 91 \text{ mW} \div 5.5 \text{ mA} = 16.5 \text{ V}$ The result indicates that, at  $T_A$ , the application and device can dissipate adequate amounts of heat at voltages  $\leq V_{CC}(est)$ .

Compare  $V_{CC}(est)$  to  $V_{CC}(max)$ . If  $V_{CC}(est) \le V_{CC}(max)$ , then reliable operation between  $V_{CC}(est)$  and  $V_{CC}(max)$  requires enhanced  $R_{\theta JA}$ . If  $V_{CC}(est) \ge V_{CC}(max)$ , then operation between  $V_{CC}(est)$  and  $V_{CC}(max)$  is reliable under these conditions.



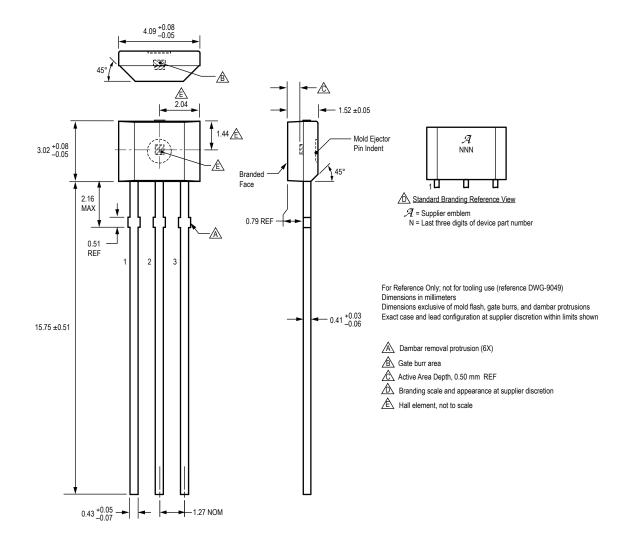
# Package Outline Drawings

Package LT 3-Pin SOT-89





Package UA 3-Pin SIP





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